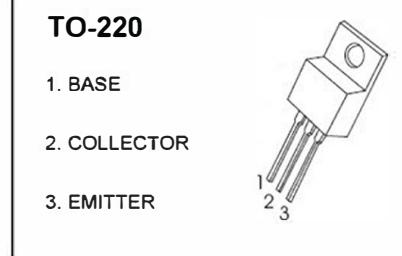


TO-220 Plastic-Encapsulate Transistors

TIP41/41A/41B/41C TRANSISTOR (NPN)

FEATURES

Medium Power Linear Switching Applications



MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	TIP41	TIP41A	TIP41B	TIP41C	Unit
V_{CBO}	Collector-Base Voltage	40	60	80	100	V
V_{CEO}	Collector-Emitter Voltage	40	60	80	100	V
V_{EBO}	Emitter-Base Voltage			5		V
I_c	Collector Current -Continuous			6		A
P_c	Collector Power Dissipation			2		W
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient			62.5		$^\circ\text{C}/\text{W}$
T_J, T_{stg}	Operation Junction and Storage Temperature Range			-55~+150		$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_c = 1\text{mA}, I_E = 0$	40		V
			60		
			80		
			100		
Collector-emitter breakdown voltage	$V_{CEO(sus)}$	$I_C = 30\text{mA}, I_B = 0$	40		V
			60		
			80		
			100		
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = 1\text{mA}, I_C = 0$	5		V
Collector cut-off current	I_{CBO}	$V_{CB}=40\text{V}, I_E=0$ $V_{CB}=60\text{V}, I_E=0$ $V_{CB}=80\text{V}, I_E=0$ $V_{CB}=100\text{V}, I_E=0$		0.4	mA
Collector cut-off current	I_{CEO}	$V_{CE} = 30\text{V}, I_B = 0$ $V_{CE} = 60\text{V}, I_B = 0$		0.7	mA
Emitter cut-off current	I_{EBO}	$V_{EB}=5\text{V}, I_C=0$		1	mA
DC current gain	$h_{FE(1)}$	$V_{CE} = 4\text{V}, I_C = 0.3\text{A}$	30		
	$h_{FE(2)}$	$V_{CE} = 4\text{V}, I_C = 3\text{A}$	15	75	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 6\text{A}, I_B = 0.6\text{A}$		1.5	V
Base-emitter voltage	$V_{BE(on)}$	$V_{CE} = 4\text{V}, I_C = 6\text{A}$		2	V
Transition frequency	f_T	$V_{CE} = 10\text{V}, I_C = 0.5\text{A}$ $f = 1\text{MHz}$	3		MHz

